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### What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

### Applications of "[Embedded - Microcontrollers](#)"

Details	
Product Status	Obsolete
Core Processor	RL78
Core Size	16-Bit
Speed	32MHz
Connectivity	CSI, I <sup>2</sup> C, LINbus, UART/USART
Peripherals	DMA, LVD, POR, PWM, WDT
Number of I/O	48
Program Memory Size	192KB (192K x 8)
Program Memory Type	FLASH
EEPROM Size	8K x 8
RAM Size	16K x 8
Voltage - Supply (Vcc/Vdd)	1.6V ~ 5.5V
Data Converters	A/D 12x8/10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	64-LQFP
Supplier Device Package	64-LQFP (12x12)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f100lhgfa-v0">https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f100lhgfa-v0</a>

**Table 1-1. List of Ordering Part Numbers**

(11/12)

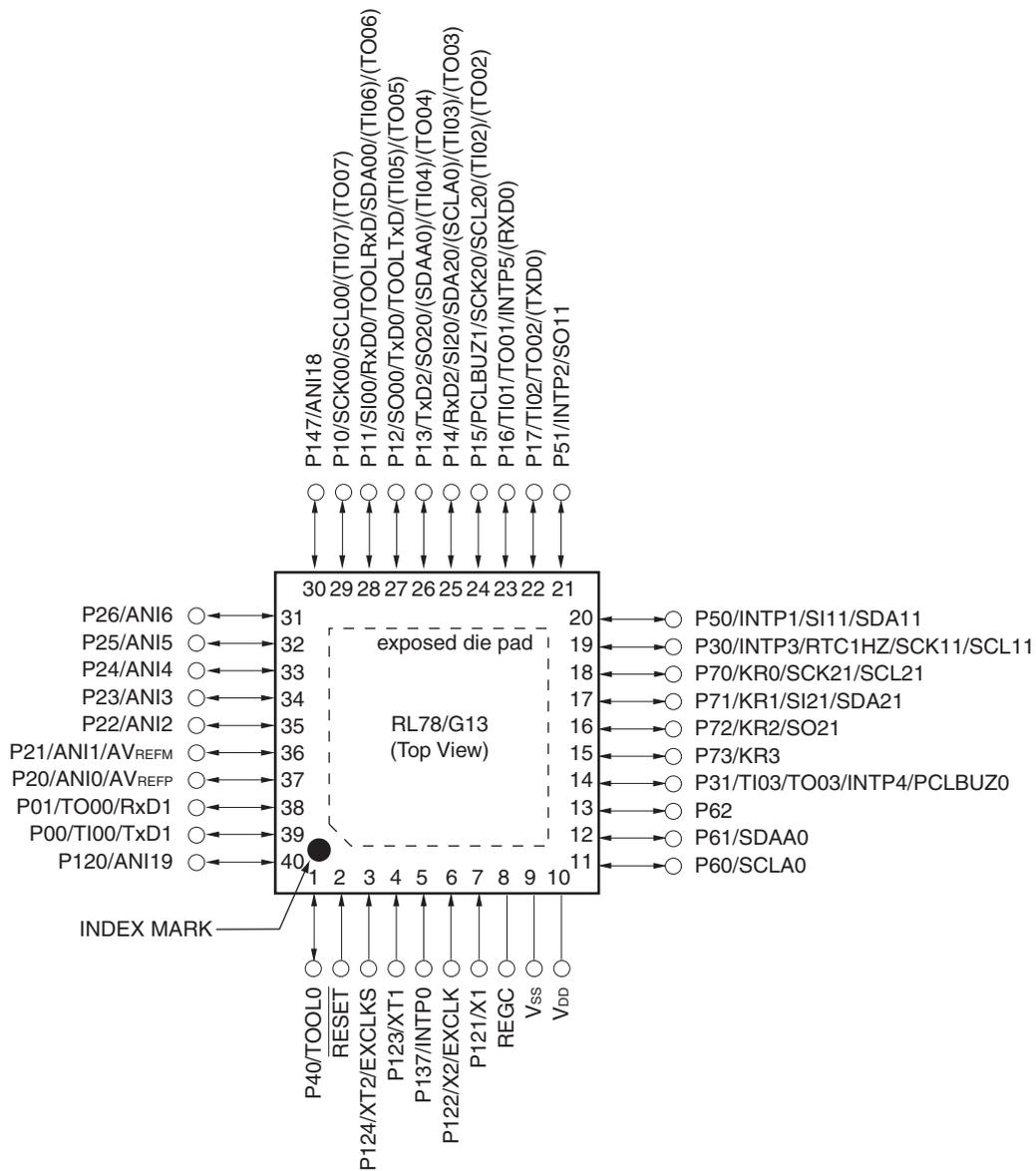
Pin count	Package	Data flash	Fields of Application <small>Note</small>	Ordering Part Number
100 pins	100-pin plastic LFQFP (14 × 14 mm, 0.5 mm pitch)	Mounted	A	R5F100PFAFB#V0, R5F100PGAFB#V0, R5F100PHAFB#V0, R5F100PJAFB#V0, R5F100PKAFB#V0, R5F100PLAFB#V0 R5F100PFAFB#X0, R5F100PGAFB#X0, R5F100PHAFB#X0, R5F100PJAFB#X0, R5F100PKAFB#X0, R5F100PLAFB#X0
			D	R5F100PFDFB#V0, R5F100PGDFB#V0, R5F100PHDFB#V0, R5F100PJDFB#V0, R5F100PKDFB#V0, R5F100PLDFB#V0 R5F100PFDFB#X0, R5F100PGDFB#X0, R5F100PHDFB#X0, R5F100PJDFB#X0, R5F100PKDFB#X0, R5F100PLDFB#X0
		G	R5F100PFGFB#V0, R5F100PGGFB#V0, R5F100PHGFB#V0, R5F100PJGFB#V0 R5F100PFGFB#X0, R5F100PGGFB#X0, R5F100PHGFB#X0, R5F100PJGFB#X0	
	Not mounted	A	R5F101PFAFB#V0, R5F101PGAFB#V0, R5F101PHAFB#V0, R5F101PJAFB#V0, R5F101PKAFB#V0, R5F101PLAFB#V0 R5F101PFAFB#X0, R5F101PGAFB#X0, R5F101PHAFB#X0, R5F101PJAFB#X0, R5F101PKAFB#X0, R5F101PLAFB#X0	
		D	R5F101PFDFB#V0, R5F101PGDFB#V0, R5F101PHDFB#V0, R5F101PJDFB#V0, R5F101PKDFB#V0, R5F101PLDFB#V0 R5F101PFDFB#X0, R5F101PGDFB#X0, R5F101PHDFB#X0, R5F101PJDFB#X0, R5F101PKDFB#X0, R5F101PLDFB#X0	
	100-pin plastic LQFP (14 × 20 mm, 0.65 mm pitch)	Mounted	A	R5F100PFafa#V0, R5F100PGafa#V0, R5F100PHafa#V0, R5F100PJafa#V0, R5F100PKafa#V0, R5F100PLafa#V0 R5F100PFafa#X0, R5F100PGafa#X0, R5F100PHafa#X0, R5F100PJafa#X0, R5F100PKafa#X0, R5F100PLafa#X0
			D	R5F100PFdFa#V0, R5F100PGdFa#V0, R5F100PHdFa#V0, R5F100PJdFa#V0, R5F100PKdFa#V0, R5F100PLdFa#V0 R5F100PFdFa#X0, R5F100PGdFa#X0, R5F100PHdFa#X0, R5F100PJdFa#X0, R5F100PKdFa#X0, R5F100PLdFa#X0
		G	R5F100PFGfa#V0, R5F100PGGfa#V0, R5F100PHGfa#V0, R5F100PJGfa#V0 R5F100PFGfa#X0, R5F100PGGfa#X0, R5F100PHGfa#X0, R5F100PJGfa#X0	
	Not mounted	A	R5F101PFafa#V0, R5F101PGafa#V0, R5F101PHafa#V0, R5F101PJafa#V0, R5F101PKafa#V0, R5F101PLafa#V0 R5F101PFafa#X0, R5F101PGafa#X0, R5F101PHafa#X0, R5F101PJafa#X0, R5F101PKafa#X0, R5F101PLafa#X0	
		D	R5F101PFdFa#V0, R5F101PGdFa#V0, R5F101PHdFa#V0, R5F101PJdFa#V0, R5F101PKdFa#V0, R5F101PLdFa#V0 R5F101PFdFa#X0, R5F101PGdFa#X0, R5F101PHdFa#X0, R5F101PJdFa#X0, R5F101PKdFa#X0, R5F101PLdFa#X0	

**Note** For the fields of application, refer to **Figure 1-1 Part Number, Memory Size, and Package of RL78/G13**.

**Caution** The ordering part numbers represent the numbers at the time of publication. For the latest ordering part numbers, refer to the target product page of the Renesas Electronics website.

1.3.7 40-pin products

- 40-pin plastic HWQFN (6 × 6 mm, 0.5 mm pitch)

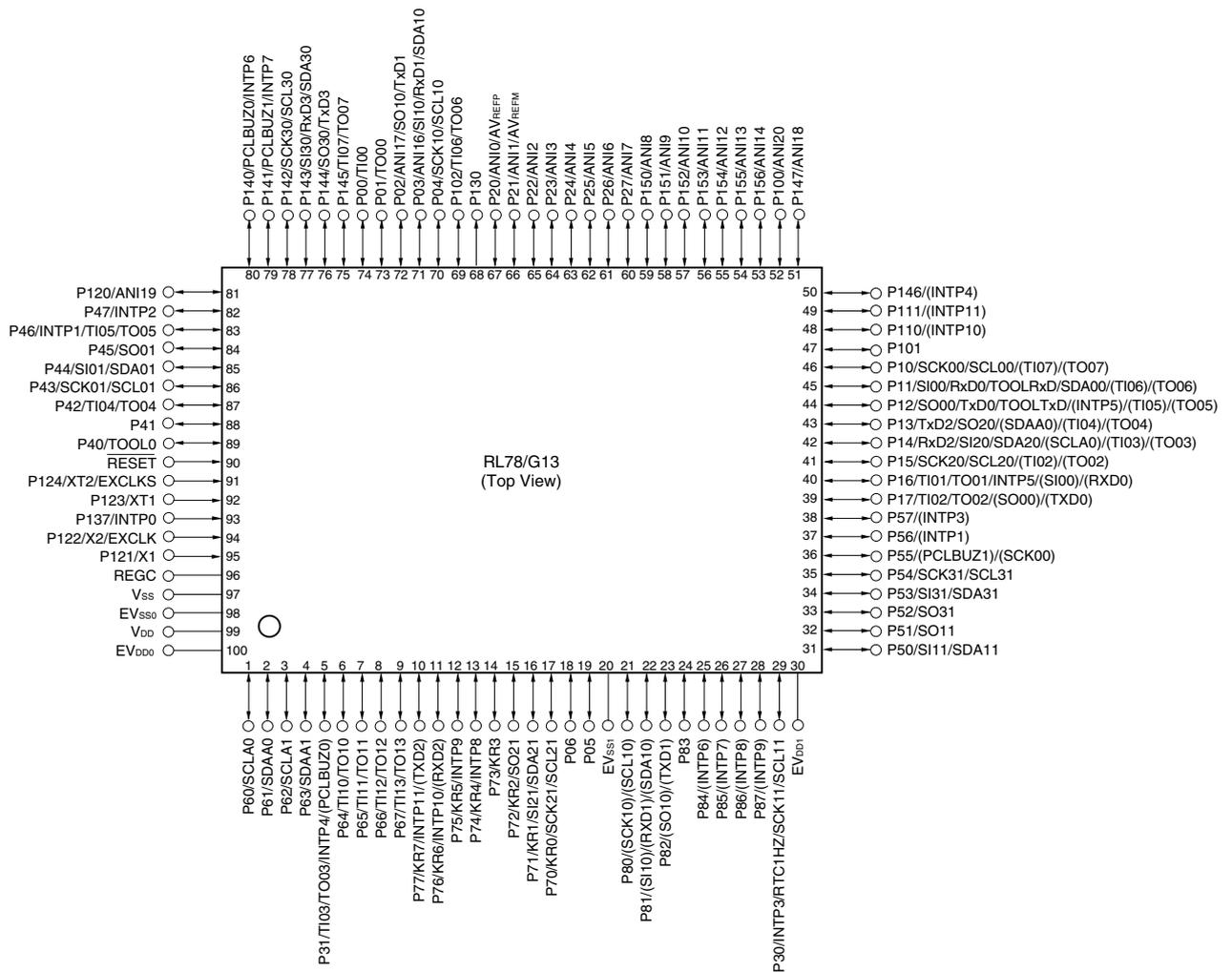


**Caution** Connect the REGC pin to V<sub>SS</sub> via a capacitor (0.47 to 1 μF).

**Remarks 1.** For pin identification, see 1.4 Pin Identification.

- Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register (PIOR). Refer to **Figure 4-8 Format of Peripheral I/O Redirection Register (PIOR)** in the RL78/G13 User's Manual.
- It is recommended to connect an exposed die pad to V<sub>SS</sub>.

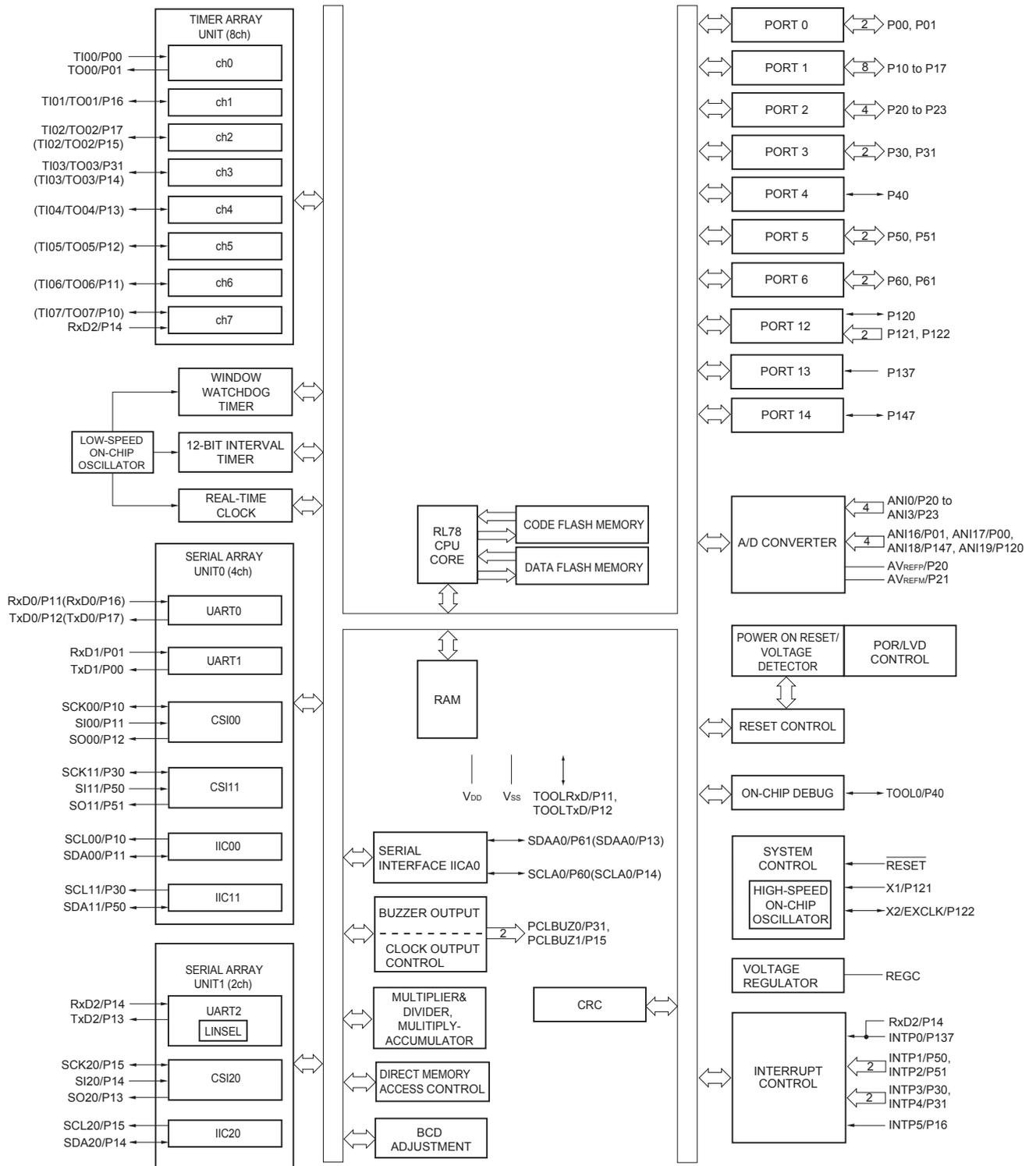
- 100-pin plastic LQFP (14 × 20 mm, 0.65 mm pitch)



- Cautions**
1. Make EV<sub>SS0</sub>, EV<sub>SS1</sub> pins the same potential as V<sub>SS</sub> pin.
  2. Make V<sub>DD</sub> pin the potential that is higher than EV<sub>DD0</sub>, EV<sub>DD1</sub> pins (EV<sub>DD0</sub> = EV<sub>DD1</sub>).
  3. Connect the REGC pin to V<sub>SS</sub> via a capacitor (0.47 to 1 μF).

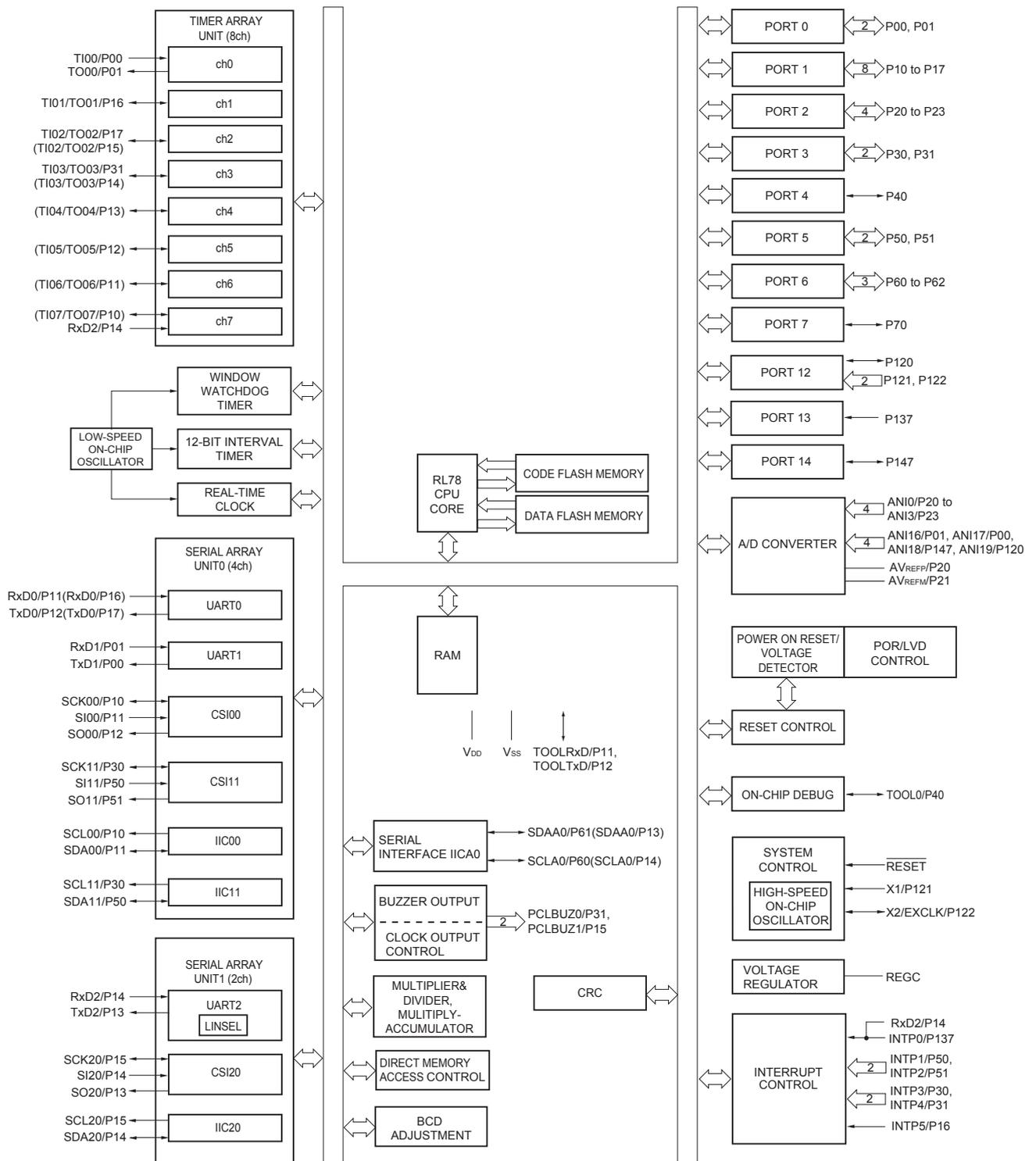
- Remarks**
1. For pin identification, see 1.4 Pin Identification.
  2. When using the microcontroller for an application where the noise generated inside the microcontroller must be reduced, it is recommended to supply separate powers to the V<sub>DD</sub>, EV<sub>DD0</sub> and EV<sub>DD1</sub> pins and connect the V<sub>SS</sub>, EV<sub>SS0</sub> and EV<sub>SS1</sub> pins to separate ground lines.
  3. Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register (PIOR). Refer to **Figure 4-8 Format of Peripheral I/O Redirection Register (PIOR)** in the RL78/G13 User's Manual.

1.5.4 30-pin products



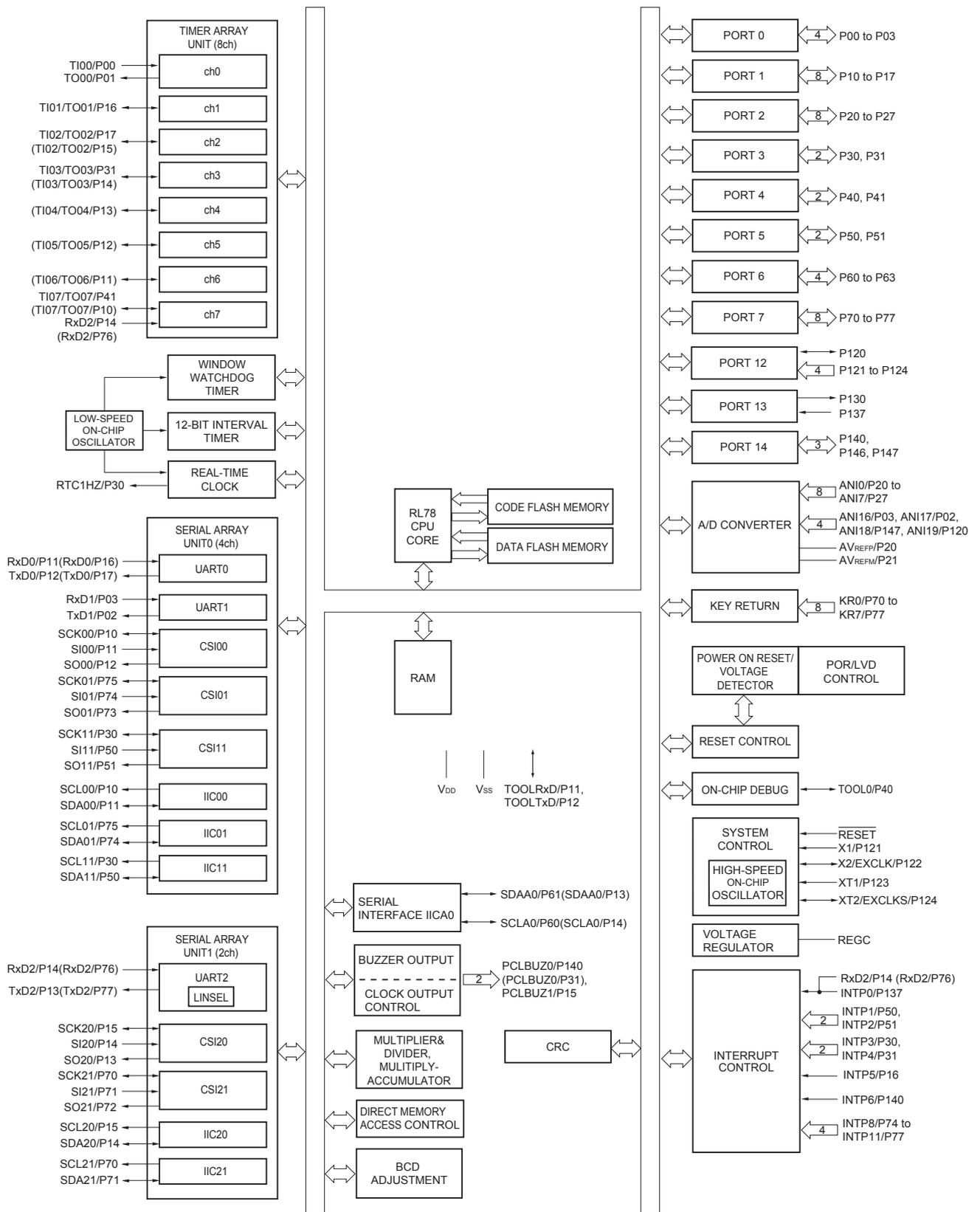
**Remark** Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register (PIOR). Refer to **Figure 4-8 Format of Peripheral I/O Redirection Register (PIOR)** in the RL78/G13 User's Manual.

1.5.5 32-pin products



**Remark** Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register (PIOR). Refer to **Figure 4-8 Format of Peripheral I/O Redirection Register (PIOR)** in the RL78/G13 User's Manual.

1.5.10 52-pin products



**Remark** Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register (PIOR). Refer to **Figure 4-8 Format of Peripheral I/O Redirection Register (PIOR)** in the RL78/G13 User's Manual.

[40-pin, 44-pin, 48-pin, 52-pin, 64-pin products]

**Caution** This outline describes the functions at the time when Peripheral I/O redirection register (PIOR) is set to 00H.

(1/2)

Item		40-pin		44-pin		48-pin		52-pin		64-pin			
		R5F100Ex	R5F101Ex	R5F100Fx	R5F101Fx	R5F100Gx	R5F101Gx	R5F100Jx	R5F101Jx	R5F100Lx	R5F101Lx		
Code flash memory (KB)		16 to 192		16 to 512		16 to 512		32 to 512		32 to 512			
Data flash memory (KB)		4 to 8	–	4 to 8	–	4 to 8	–	4 to 8	–	4 to 8	–		
RAM (KB)		2 to 16 <sup>Note1</sup>		2 to 32 <sup>Note1</sup>		2 to 32 <sup>Note1</sup>		2 to 32 <sup>Note1</sup>		2 to 32 <sup>Note1</sup>			
Address space		1 MB											
Main system clock	High-speed system clock	X1 (crystal/ceramic) oscillation, external main system clock input (EXCLK) HS (High-speed main) mode: 1 to 20 MHz (V <sub>DD</sub> = 2.7 to 5.5 V), HS (High-speed main) mode: 1 to 16 MHz (V <sub>DD</sub> = 2.4 to 5.5 V), LS (Low-speed main) mode: 1 to 8 MHz (V <sub>DD</sub> = 1.8 to 5.5 V), LV (Low-voltage main) mode: 1 to 4 MHz (V <sub>DD</sub> = 1.6 to 5.5 V)											
	High-speed on-chip oscillator	HS (High-speed main) mode: 1 to 32 MHz (V <sub>DD</sub> = 2.7 to 5.5 V), HS (High-speed main) mode: 1 to 16 MHz (V <sub>DD</sub> = 2.4 to 5.5 V), LS (Low-speed main) mode: 1 to 8 MHz (V <sub>DD</sub> = 1.8 to 5.5 V), LV (Low-voltage main) mode: 1 to 4 MHz (V <sub>DD</sub> = 1.6 to 5.5 V)											
Subsystem clock		XT1 (crystal) oscillation, external subsystem clock input (EXCLKS) 32.768 kHz											
Low-speed on-chip oscillator		15 kHz (TYP.)											
General-purpose registers		(8-bit register × 8) × 4 banks											
Minimum instruction execution time		0.03125 μs (High-speed on-chip oscillator: f <sub>IH</sub> = 32 MHz operation)											
		0.05 μs (High-speed system clock: f <sub>MX</sub> = 20 MHz operation)											
		30.5 μs (Subsystem clock: f <sub>SUB</sub> = 32.768 kHz operation)											
Instruction set		<ul style="list-style-type: none"> <li>• Data transfer (8/16 bits)</li> <li>• Adder and subtractor/logical operation (8/16 bits)</li> <li>• Multiplication (8 bits × 8 bits)</li> <li>• Rotate, barrel shift, and bit manipulation (Set, reset, test, and Boolean operation), etc.</li> </ul>											
I/O port	Total	36		40		44		48		58			
	CMOS I/O	28 (N-ch O.D. I/O [V <sub>DD</sub> withstand voltage]: 10)		31 (N-ch O.D. I/O [V <sub>DD</sub> withstand voltage]: 10)		34 (N-ch O.D. I/O [V <sub>DD</sub> withstand voltage]: 11)		38 (N-ch O.D. I/O [V <sub>DD</sub> withstand voltage]: 13)		48 (N-ch O.D. I/O [V <sub>DD</sub> withstand voltage]: 15)			
	CMOS input	5		5		5		5		5			
	CMOS output	–		–		1		1		1			
	N-ch O.D. I/O (withstand voltage: 6 V)	3		4		4		4		4			
Timer	16-bit timer	8 channels											
	Watchdog timer	1 channel											
	Real-time clock (RTC)	1 channel											
	12-bit interval timer (IT)	1 channel											
	Timer output	4 channels (PWM outputs: 3 <sup>Note2</sup> ), 8 channels (PWM outputs: 7 <sup>Note2, Note3</sup> )		5 channels (PWM outputs: 4 <sup>Note2</sup> ), 8 channels (PWM outputs: 7 <sup>Note2, Note3</sup> ) <sup>Note3</sup>						8 channels (PWM outputs: 7 <sup>Note2</sup> )			
	RTC output	1 channel • 1 Hz (subsystem clock: f <sub>SUB</sub> = 32.768 kHz)											

**Notes 1.** The flash library uses RAM in self-programming and rewriting of the data flash memory. The target products and start address of the RAM areas used by the flash library are shown below.  
 R5F100xD, R5F101xD (x = E to G, J, L): Start address FF300H  
 R5F100xE, R5F101xE (x = E to G, J, L): Start address FEF00H  
 R5F100xJ, R5F101xJ (x = F, G, J, L): Start address FAF00H  
 R5F100xL, R5F101xL (x = F, G, J, L): Start address F7F00H  
 For the RAM areas used by the flash library, see **Self RAM list of Flash Self-Programming Library for RL78 Family (R2OUT2944)**.

## 2. ELECTRICAL SPECIFICATIONS ( $T_A = -40$ to $+85^\circ\text{C}$ )

This chapter describes the following electrical specifications.

Target products A: Consumer applications  $T_A = -40$  to  $+85^\circ\text{C}$

R5F100xxAxx, R5F101xxAxx

D: Industrial applications  $T_A = -40$  to  $+85^\circ\text{C}$

R5F100xxDxx, R5F101xxDxx

G: Industrial applications when  $T_A = -40$  to  $+105^\circ\text{C}$  products is used in the range of  $T_A = -40$  to  $+85^\circ\text{C}$

R5F100xxGxx

- Cautions**
- 1. The RL78 microcontrollers have an on-chip debug function, which is provided for development and evaluation. Do not use the on-chip debug function in products designated for mass production, because the guaranteed number of rewritable times of the flash memory may be exceeded when this function is used, and product reliability therefore cannot be guaranteed. Renesas Electronics is not liable for problems occurring when the on-chip debug function is used.**
  - 2. With products not provided with an  $EV_{DD0}$ ,  $EV_{DD1}$ ,  $EV_{SS0}$ , or  $EV_{SS1}$  pin, replace  $EV_{DD0}$  and  $EV_{DD1}$  with  $V_{DD}$ , or replace  $EV_{SS0}$  and  $EV_{SS1}$  with  $V_{SS}$ .**
  - 3. The pins mounted depend on the product. Refer to 2.1 Port Function to 2.2.1 Functions for each product.**

- Notes**
1. Total current flowing into V<sub>DD</sub> and EV<sub>DD0</sub>, including the input leakage current flowing when the level of the input pin is fixed to V<sub>DD</sub>, EV<sub>DD0</sub> or V<sub>SS</sub>, EV<sub>SS0</sub>. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.
  2. During HALT instruction execution by flash memory.
  3. When high-speed on-chip oscillator and subsystem clock are stopped.
  4. When high-speed system clock and subsystem clock are stopped.
  5. When high-speed on-chip oscillator and high-speed system clock are stopped. When RTCLPC = 1 and setting ultra-low current consumption (AMPHS1 = 1). The current flowing into the RTC is included. However, not including the current flowing into the 12-bit interval timer and watchdog timer.
  6. Not including the current flowing into the RTC, 12-bit interval timer, and watchdog timer.
  7. Relationship between operation voltage width, operation frequency of CPU and operation mode is as below.
    - HS (high-speed main) mode:  $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V} @ 1\text{ MHz to } 32\text{ MHz}$   
 $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V} @ 1\text{ MHz to } 16\text{ MHz}$
    - LS (low-speed main) mode:  $1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V} @ 1\text{ MHz to } 8\text{ MHz}$
    - LV (low-voltage main) mode:  $1.6\text{ V} \leq V_{DD} \leq 5.5\text{ V} @ 1\text{ MHz to } 4\text{ MHz}$
  8. Regarding the value for current to operate the subsystem clock in STOP mode, refer to that in HALT mode.

- Remarks**
1. f<sub>MX</sub>: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)
  2. f<sub>IH</sub>: High-speed on-chip oscillator clock frequency
  3. f<sub>SUB</sub>: Subsystem clock frequency (XT1 clock oscillation frequency)
  4. Except subsystem clock operation and STOP mode, temperature condition of the TYP. value is T<sub>A</sub> = 25°C

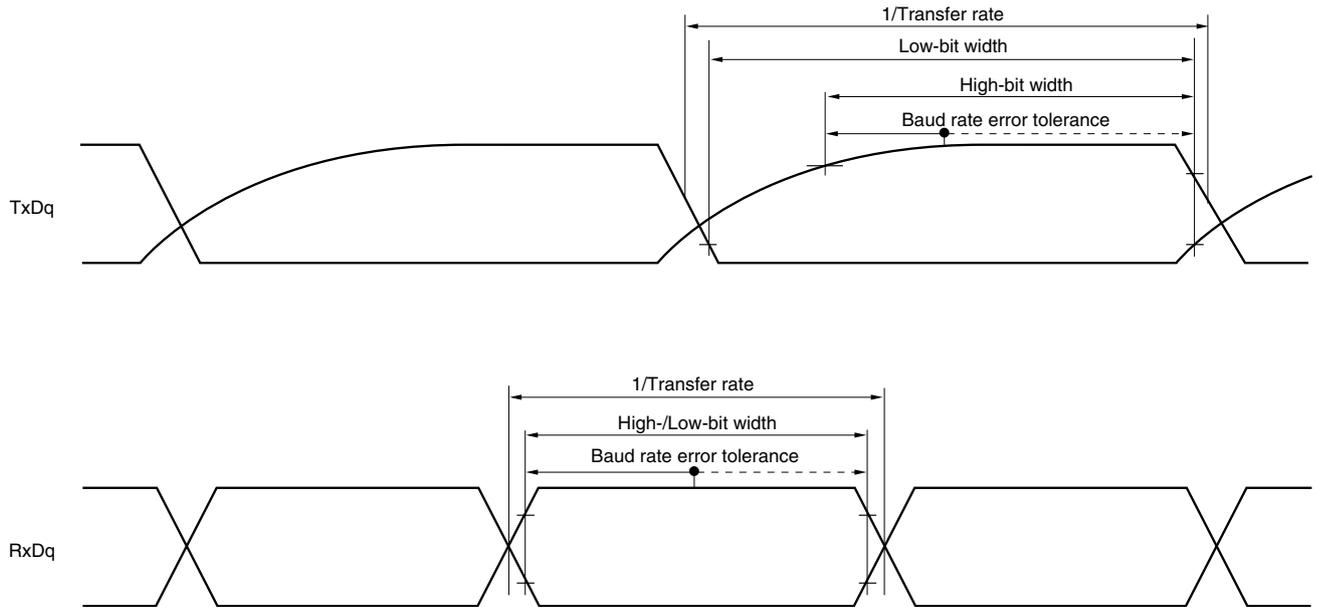
- Remarks 1.** p: CSI number (p = 00, 01, 10, 11, 20, 21, 30, 31), m: Unit number (m = 0, 1), n: Channel number (n = 0 to 3),  
 g: PIM and POM numbers (g = 0, 1, 4, 5, 8, 14)
- 2.** f<sub>MCK</sub>: Serial array unit operation clock frequency  
 (Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00 to 03, 10 to 13))

**(4) During communication at same potential (CSI mode) (slave mode, SCKp... external clock input) (1/2)**  
 (T<sub>A</sub> = -40 to +85°C, 1.6 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V)

Parameter	Symbol	Conditions	HS (high-speed main) Mode		LS (low-speed main) Mode		LV (low-voltage main) Mode		Unit	
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.		
SCKp cycle time <small>Note 5</small>	t <sub>KCY2</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	20 MHz < f <sub>MCK</sub>	8/f <sub>MCK</sub>		—		—	ns	
			f <sub>MCK</sub> ≤ 20 MHz	6/f <sub>MCK</sub>		6/f <sub>MCK</sub>		6/f <sub>MCK</sub>	ns	
		2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	16 MHz < f <sub>MCK</sub>	8/f <sub>MCK</sub>		—		—	ns	
			f <sub>MCK</sub> ≤ 16 MHz	6/f <sub>MCK</sub>		6/f <sub>MCK</sub>		6/f <sub>MCK</sub>	ns	
		2.4 V ≤ EV <sub>DD0</sub> ≤ 5.5 V			6/f <sub>MCK</sub> and 500		6/f <sub>MCK</sub> and 500		6/f <sub>MCK</sub> and 500	ns
		1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V			6/f <sub>MCK</sub> and 750		6/f <sub>MCK</sub> and 750		6/f <sub>MCK</sub> and 750	ns
		1.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V			6/f <sub>MCK</sub> and 1500		6/f <sub>MCK</sub> and 1500		6/f <sub>MCK</sub> and 1500	ns
		1.6 V ≤ EV <sub>DD0</sub> ≤ 5.5 V			—		6/f <sub>MCK</sub> and 1500		6/f <sub>MCK</sub> and 1500	ns
SCKp high-/low-level width	t <sub>KH2</sub> , t <sub>KL2</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		t <sub>KCY2</sub> /2 – 7		t <sub>KCY2</sub> /2 – 7		t <sub>KCY2</sub> /2 – 7	ns	
		2.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		t <sub>KCY2</sub> /2 – 8		t <sub>KCY2</sub> /2 – 8		t <sub>KCY2</sub> /2 – 8	ns	
		1.8 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		t <sub>KCY2</sub> /2 – 18		t <sub>KCY2</sub> /2 – 18		t <sub>KCY2</sub> /2 – 18	ns	
		1.7 V ≤ EV <sub>DD0</sub> ≤ 5.5 V		t <sub>KCY2</sub> /2 – 66		t <sub>KCY2</sub> /2 – 66		t <sub>KCY2</sub> /2 – 66	ns	
		1.6 V ≤ EV <sub>DD0</sub> ≤ 5.5 V			—	t <sub>KCY2</sub> /2 – 66		t <sub>KCY2</sub> /2 – 66	ns	

(Notes, Caution, and Remarks are listed on the next page.)

### UART mode bit width (during communication at different potential) (reference)



- Remarks**
1.  $R_b[\Omega]$ : Communication line (TxDq) pull-up resistance,  
 $C_b[\text{F}]$ : Communication line (TxDq) load capacitance,  $V_b[\text{V}]$ : Communication line voltage
  2. q: UART number (q = 0 to 3), g: PIM and POM number (g = 0, 1, 8, 14)
  3.  $f_{\text{MCK}}$ : Serial array unit operation clock frequency  
 (Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn).  
 m: Unit number, n: Channel number (mn = 00 to 03, 10 to 13))
  4. UART2 cannot communicate at different potential when bit 1 (PIOR1) of peripheral I/O redirection register (PIOR) is 1.

**(8) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (master mode, SCKp... internal clock output)**  
**(1/3)****(T<sub>A</sub> = -40 to +85°C, 1.8 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V)**

Parameter	Symbol	Conditions	HS (high-speed main) Mode		LS (low-speed main) Mode		LV (low-voltage main) Mode		Unit
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
SCKp cycle time	t <sub>KCY1</sub>	t <sub>KCY1</sub> ≥ 4/f <sub>CLK</sub> 4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 1.4 kΩ	300		1150		1150		ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 2.7 kΩ	500		1150		1150		ns
		1.8 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V <sup>Note</sup> , C <sub>b</sub> = 30 pF, R <sub>b</sub> = 5.5 kΩ	1150		1150		1150		ns
SCKp high-level width	t <sub>KH1</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 1.4 kΩ	t <sub>KCY1</sub> /2 – 75		t <sub>KCY1</sub> /2 – 75		t <sub>KCY1</sub> /2 – 75		ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 2.7 kΩ	t <sub>KCY1</sub> /2 – 170		t <sub>KCY1</sub> /2 – 170		t <sub>KCY1</sub> /2 – 170		ns
		1.8 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V <sup>Note</sup> , C <sub>b</sub> = 30 pF, R <sub>b</sub> = 5.5 kΩ	t <sub>KCY1</sub> /2 – 458		t <sub>KCY1</sub> /2 – 458		t <sub>KCY1</sub> /2 – 458		ns
SCKp low-level width	t <sub>KL1</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 1.4 kΩ	t <sub>KCY1</sub> /2 – 12		t <sub>KCY1</sub> /2 – 50		t <sub>KCY1</sub> /2 – 50		ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 2.7 kΩ	t <sub>KCY1</sub> /2 – 18		t <sub>KCY1</sub> /2 – 50		t <sub>KCY1</sub> /2 – 50		ns
		1.8 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V <sup>Note</sup> , C <sub>b</sub> = 30 pF, R <sub>b</sub> = 5.5 kΩ	t <sub>KCY1</sub> /2 – 50		t <sub>KCY1</sub> /2 – 50		t <sub>KCY1</sub> /2 – 50		ns

**Note** Use it with EV<sub>DD0</sub> ≥ V<sub>b</sub>.**Caution** Select the TTL input buffer for the SIp pin and the N-ch open drain output (V<sub>DD</sub> tolerance (When 20- to 52-pin products)/EV<sub>DD</sub> tolerance (When 64- to 128-pin products)) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V<sub>IH</sub> and V<sub>IL</sub>, see the DC characteristics with TTL input buffer selected.

(Remarks are listed two pages after the next page.)

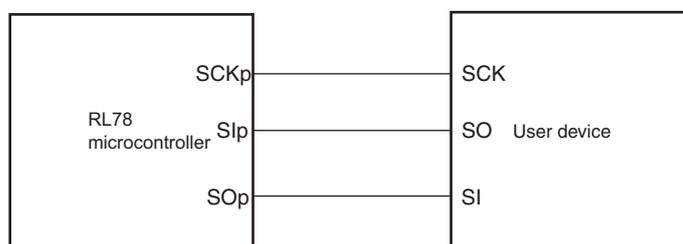
**(3) During communication at same potential (CSI mode) (slave mode, SCKp... external clock input)****( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq \text{EV}_{\text{DD}0} = \text{EV}_{\text{DD}1} \leq \text{V}_{\text{DD}} \leq 5.5\text{ V}$ ,  $\text{V}_{\text{SS}} = \text{EV}_{\text{SS}0} = \text{EV}_{\text{SS}1} = 0\text{ V}$ )**

Parameter	Symbol	Conditions	HS (high-speed main) Mode		Unit	
			MIN.	MAX.		
SCKp cycle time <sup>Note 5</sup>	$t_{\text{KCY}2}$	$4.0\text{ V} \leq \text{EV}_{\text{DD}0} \leq 5.5\text{ V}$	$20\text{ MHz} < f_{\text{MCK}}$	$16/f_{\text{MCK}}$	ns	
			$f_{\text{MCK}} \leq 20\text{ MHz}$	$12/f_{\text{MCK}}$	ns	
		$2.7\text{ V} \leq \text{EV}_{\text{DD}0} \leq 5.5\text{ V}$	$16\text{ MHz} < f_{\text{MCK}}$	$16/f_{\text{MCK}}$	ns	
			$f_{\text{MCK}} \leq 16\text{ MHz}$	$12/f_{\text{MCK}}$	ns	
		$2.4\text{ V} \leq \text{EV}_{\text{DD}0} \leq 5.5\text{ V}$		$16/f_{\text{MCK}}$	ns	
	$12/f_{\text{MCK}}$ and 1000		ns			
SCKp high-/low-level width	$t_{\text{KH}2}$ , $t_{\text{KL}2}$	$4.0\text{ V} \leq \text{EV}_{\text{DD}0} \leq 5.5\text{ V}$	$t_{\text{KCY}2}/2 - 14$		ns	
		$2.7\text{ V} \leq \text{EV}_{\text{DD}0} \leq 5.5\text{ V}$	$t_{\text{KCY}2}/2 - 16$		ns	
		$2.4\text{ V} \leq \text{EV}_{\text{DD}0} \leq 5.5\text{ V}$	$t_{\text{KCY}2}/2 - 36$		ns	
Slp setup time (to SCKp $\uparrow$ ) <sup>Note 1</sup>	$t_{\text{SIK}2}$	$2.7\text{ V} \leq \text{EV}_{\text{DD}0} \leq 5.5\text{ V}$	$1/f_{\text{MCK}} + 40$		ns	
		$2.4\text{ V} \leq \text{EV}_{\text{DD}0} \leq 5.5\text{ V}$	$1/f_{\text{MCK}} + 60$		ns	
Slp hold time (from SCKp $\uparrow$ ) <sup>Note 2</sup>	$t_{\text{KSI}2}$	$2.4\text{ V} \leq \text{EV}_{\text{DD}0} \leq 5.5\text{ V}$	$1/f_{\text{MCK}} + 62$		ns	
Delay time from SCKp $\downarrow$ to SOp output <sup>Note 3</sup>	$t_{\text{KS}02}$	$C = 30\text{ pF}$ <sup>Note 4</sup>	$2.7\text{ V} \leq \text{EV}_{\text{DD}0} \leq 5.5\text{ V}$		$2/f_{\text{MCK}} + 66$	ns
			$2.4\text{ V} \leq \text{EV}_{\text{DD}0} \leq 5.5\text{ V}$		$2/f_{\text{MCK}} + 113$	ns

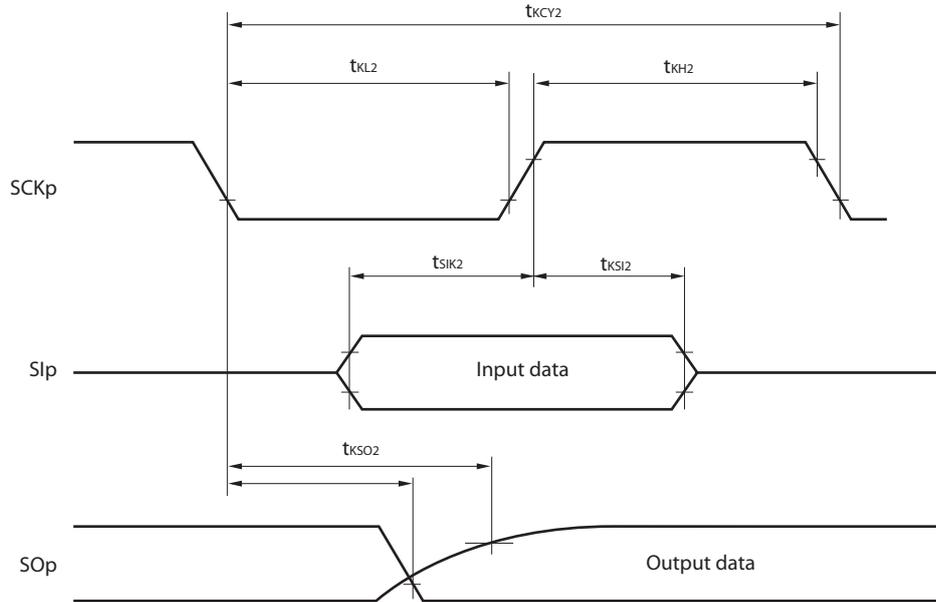
- Notes**
- When  $\text{DAP}_{\text{mn}} = 0$  and  $\text{CKP}_{\text{mn}} = 0$ , or  $\text{DAP}_{\text{mn}} = 1$  and  $\text{CKP}_{\text{mn}} = 1$ . The Slp setup time becomes “to SCKp $\downarrow$ ” when  $\text{DAP}_{\text{mn}} = 0$  and  $\text{CKP}_{\text{mn}} = 1$ , or  $\text{DAP}_{\text{mn}} = 1$  and  $\text{CKP}_{\text{mn}} = 0$ .
  - When  $\text{DAP}_{\text{mn}} = 0$  and  $\text{CKP}_{\text{mn}} = 0$ , or  $\text{DAP}_{\text{mn}} = 1$  and  $\text{CKP}_{\text{mn}} = 1$ . The Slp hold time becomes “from SCKp $\downarrow$ ” when  $\text{DAP}_{\text{mn}} = 0$  and  $\text{CKP}_{\text{mn}} = 1$ , or  $\text{DAP}_{\text{mn}} = 1$  and  $\text{CKP}_{\text{mn}} = 0$ .
  - When  $\text{DAP}_{\text{mn}} = 0$  and  $\text{CKP}_{\text{mn}} = 0$ , or  $\text{DAP}_{\text{mn}} = 1$  and  $\text{CKP}_{\text{mn}} = 1$ . The delay time to SOp output becomes “from SCKp $\uparrow$ ” when  $\text{DAP}_{\text{mn}} = 0$  and  $\text{CKP}_{\text{mn}} = 1$ , or  $\text{DAP}_{\text{mn}} = 1$  and  $\text{CKP}_{\text{mn}} = 0$ .
  - C is the load capacitance of the SOp output lines.
  - Transfer rate in the SNOOZE mode : MAX. 1 Mbps

**Caution** Select the normal input buffer for the Slp pin and SCKp pin and the normal output mode for the SOp pin by using port input mode register g (PIMg) and port output mode register g (POMg).

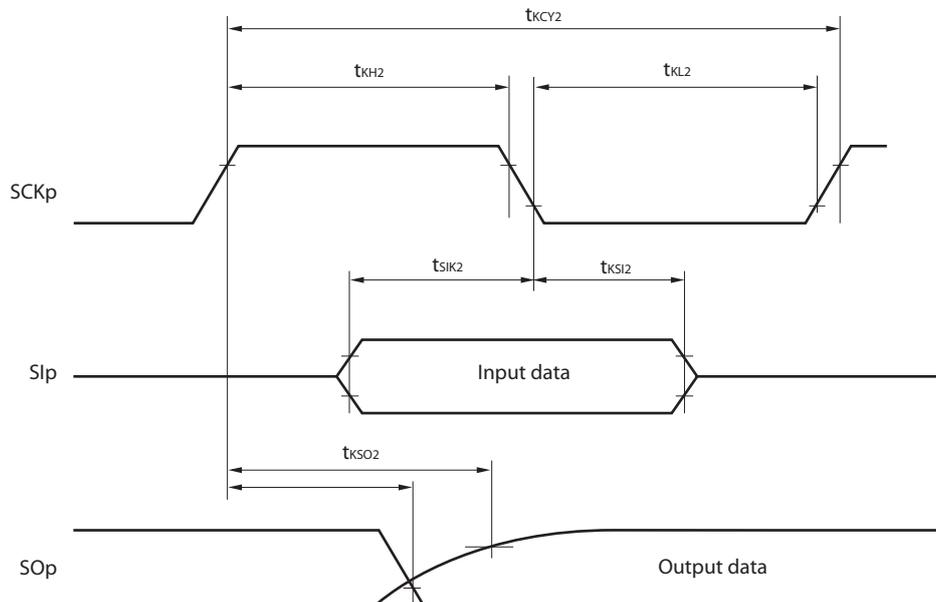
- Remarks**
- $p$ : CSI number ( $p = 00, 01, 10, 11, 20, 21, 30, 31$ ),  $m$ : Unit number ( $m = 0, 1$ ),  
 $n$ : Channel number ( $n = 0$  to  $3$ ),  $g$ : PIM number ( $g = 0, 1, 4, 5, 8, 14$ )
  - $f_{\text{MCK}}$ : Serial array unit operation clock frequency  
(Operation clock to be set by the  $\text{CKS}_{\text{mn}}$  bit of serial mode register  $\text{mn}$  ( $\text{SMR}_{\text{mn}}$ ).  $m$ : Unit number,  
 $n$ : Channel number ( $\text{mn} = 00$  to  $03, 10$  to  $13$ ))

**CSI mode connection diagram (during communication at same potential)**

**CSI mode serial transfer timing (slave mode) (during communication at different potential)  
(When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)**



**CSI mode serial transfer timing (slave mode) (during communication at different potential)  
(When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)**



- Remarks 1.** p: CSI number (p = 00, 01, 10, 20, 30, 31), m: Unit number,  
n: Channel number (mn = 00, 01, 02, 10, 12, 13), g: PIM and POM number (g = 0, 1, 4, 5, 8, 14)
- 2.** CSI01 of 48-, 52-, 64-pin products, and CSI11 and CSI21 cannot communicate at different potential.  
Use other CSI for communication at different potential.

(2) When reference voltage (+) =  $AV_{REFP}/ANI0$  ( $ADREFP1 = 0$ ,  $ADREFP0 = 1$ ), reference voltage (-) =  $AV_{REFM}/ANI1$  ( $ADREFM = 1$ ), target pin : ANI16 to ANI26

( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq EV_{DD0} = EV_{DD1} \leq V_{DD} \leq 5.5\text{ V}$ ,  $2.4\text{ V} \leq AV_{REFP} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = EV_{SS0} = EV_{SS1} = 0\text{ V}$ , Reference voltage (+) =  $AV_{REFP}$ , Reference voltage (-) =  $AV_{REFM} = 0\text{ V}$ )

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Resolution	RES		8		10	bit
Overall error <sup>Note 1</sup>	AINL	10-bit resolution $EV_{DD0} \leq AV_{REFP} = V_{DD}$ <sup>Notes 3, 4</sup>	$2.4\text{ V} \leq AV_{REFP} \leq 5.5\text{ V}$	1.2	$\pm 5.0$	LSB
Conversion time	$t_{CONV}$	10-bit resolution Target pin : ANI16 to ANI26	$3.6\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	2.125	39	$\mu\text{s}$
			$2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	3.1875	39	$\mu\text{s}$
			$2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	17	39	$\mu\text{s}$
Zero-scale error <sup>Notes 1, 2</sup>	E <sub>ZS</sub>	10-bit resolution $EV_{DD0} \leq AV_{REFP} = V_{DD}$ <sup>Notes 3, 4</sup>	$2.4\text{ V} \leq AV_{REFP} \leq 5.5\text{ V}$		$\pm 0.35$	%FSR
Full-scale error <sup>Notes 1, 2</sup>	E <sub>FS</sub>	10-bit resolution $EV_{DD0} \leq AV_{REFP} = V_{DD}$ <sup>Notes 3, 4</sup>	$2.4\text{ V} \leq AV_{REFP} \leq 5.5\text{ V}$		$\pm 0.35$	%FSR
Integral linearity error <sup>Note 1</sup>	ILE	10-bit resolution $EV_{DD0} \leq AV_{REFP} = V_{DD}$ <sup>Notes 3, 4</sup>	$2.4\text{ V} \leq AV_{REFP} \leq 5.5\text{ V}$		$\pm 3.5$	LSB
Differential linearity error <sup>Note 1</sup>	DLE	10-bit resolution $EV_{DD0} \leq AV_{REFP} = V_{DD}$ <sup>Notes 3, 4</sup>	$2.4\text{ V} \leq AV_{REFP} \leq 5.5\text{ V}$		$\pm 2.0$	LSB
Analog input voltage	V <sub>AIN</sub>	ANI16 to ANI26	0		$AV_{REFP}$ and $EV_{DD0}$	V

**Notes** 1. Excludes quantization error ( $\pm 1/2$  LSB).

2. This value is indicated as a ratio (%FSR) to the full-scale value.

3. When  $AV_{REFP} < V_{DD}$ , the MAX. values are as follows.

Overall error: Add  $\pm 1.0$  LSB to the MAX. value when  $AV_{REFP} = V_{DD}$ .

Zero-scale error/Full-scale error: Add  $\pm 0.05\%$ FSR to the MAX. value when  $AV_{REFP} = V_{DD}$ .

Integral linearity error/ Differential linearity error: Add  $\pm 0.5$  LSB to the MAX. value when  $AV_{REFP} = V_{DD}$ .

4. When  $AV_{REFP} < EV_{DD0} \leq V_{DD}$ , the MAX. values are as follows.

Overall error: Add  $\pm 4.0$  LSB to the MAX. value when  $AV_{REFP} = V_{DD}$ .

Zero-scale error/Full-scale error: Add  $\pm 0.20\%$ FSR to the MAX. value when  $AV_{REFP} = V_{DD}$ .

Integral linearity error/ Differential linearity error: Add  $\pm 2.0$  LSB to the MAX. value when  $AV_{REFP} = V_{DD}$ .

## 3.8 Flash Memory Programming Characteristics

**( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )**

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
CPU/peripheral hardware clock frequency	f <sub>CLK</sub>	$2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	1		32	MHz
Number of code flash rewrites <small>Notes 1,2,3</small>	C <sub>enwr</sub>	Retained for 20 years $T_A = 85^\circ\text{C}$ <small>Note 4</small>	1,000			Times
Number of data flash rewrites <small>Notes 1,2,3</small>		Retained for 1 years $T_A = 25^\circ\text{C}$		1,000,000		
		Retained for 5 years $T_A = 85^\circ\text{C}$ <small>Note 4</small>	100,000			
		Retained for 20 years $T_A = 85^\circ\text{C}$ <small>Note 4</small>	10,000			

- Notes**
- 1 erase + 1 write after the erase is regarded as 1 rewrite. The retaining years are until next rewrite after the rewrite.
  2. When using flash memory programmer and Renesas Electronics self programming library.
  3. These are the characteristics of the flash memory and the results obtained from reliability testing by Renesas Electronics Corporation.
  4. This temperature is the average value at which data are retained.

## 3.9 Dedicated Flash Memory Programmer Communication (UART)

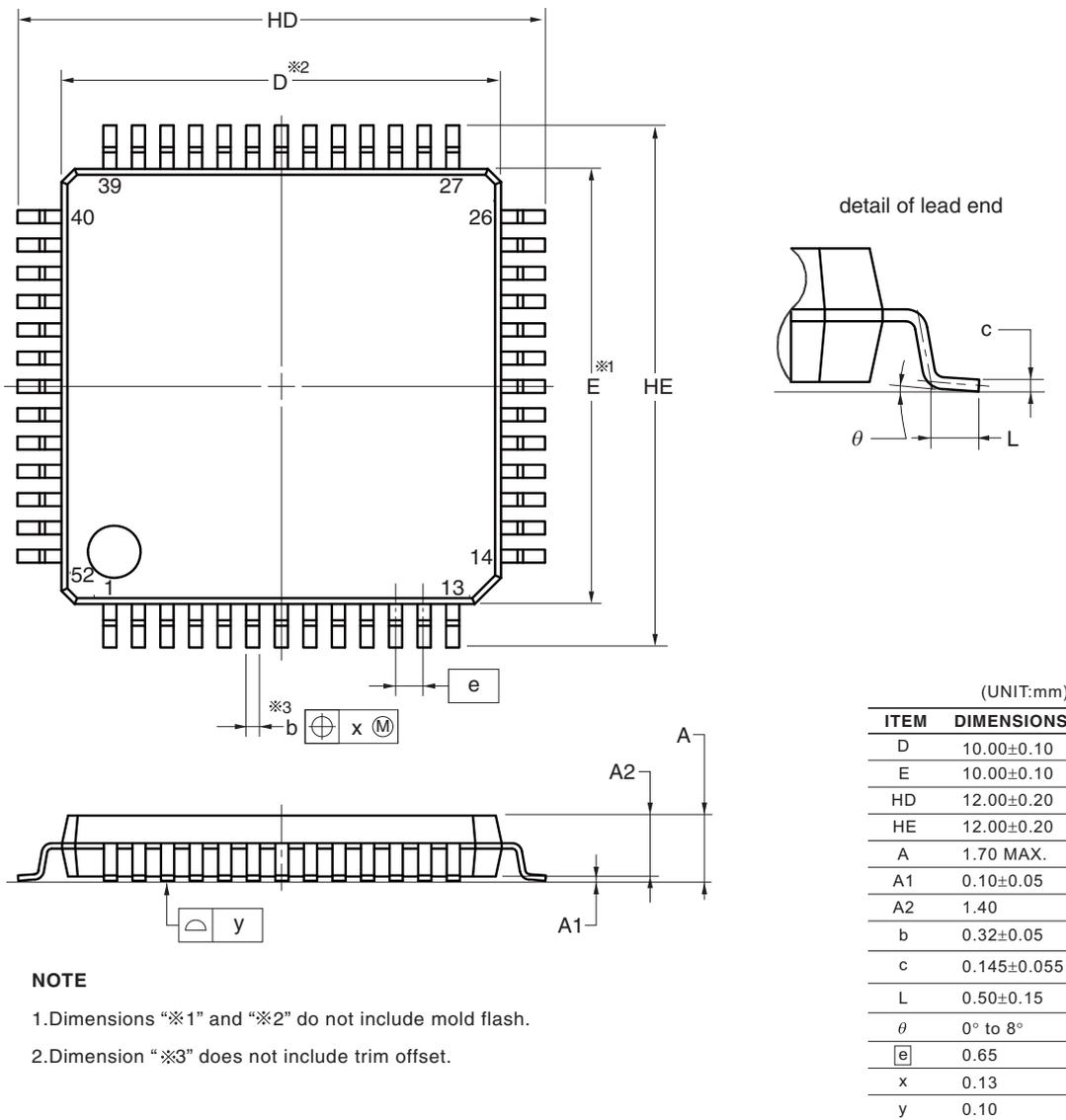
**( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq EV_{DD0} = EV_{DD1} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = EV_{SS0} = EV_{SS1} = 0\text{ V}$ )**

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Transfer rate		During serial programming	115,200		1,000,000	bps

4.10 52-pin Products

R5F100JCAFA, R5F100JDAFA, R5F100JEAFA, R5F100JFAFA, R5F100JGAFA, R5F100JHAFA, R5F100JJFAFA,  
 R5F100JKFAFA, R5F100JLAFA  
 R5F101JCAFA, R5F101JDAFA, R5F101JEAFA, R5F101JFAFA, R5F101JGAFA, R5F101JHAFA, R5F101JJFAFA,  
 R5F101JKFAFA, R5F101JLAFA  
 R5F100JCDFA, R5F100JDDFA, R5F100JEDFA, R5F100JFDFA, R5F100JGDFA, R5F100JHDFA, R5F100JJDFA,  
 R5F100JKDFA, R5F100JLDFA  
 R5F101JCDFA, R5F101JDDFA, R5F101JEDFA, R5F101JFDFA, R5F101JGDFA, R5F101JHDFA, R5F101JJDFA,  
 R5F101JKDFA, R5F101JLDFA  
 R5F100JCGFA, R5F100JDGFA, R5F100JEGFA, R5F100JFGFA, R5F100JGGFA, R5F100JHGFA, R5F100JJGFA

JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-LQFP52-10x10-0.65	PLQP0052JA-A	P52GB-65-GBS-1	0.3



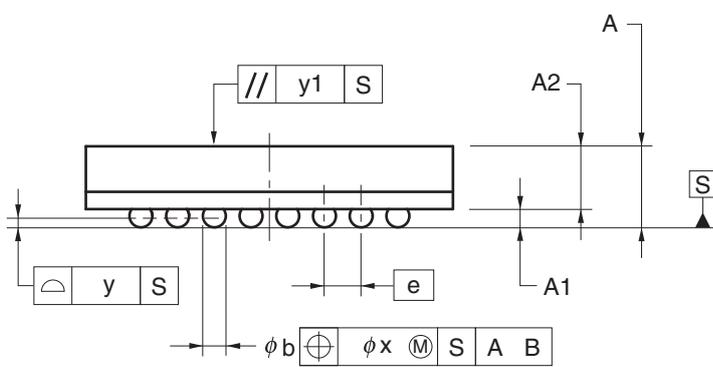
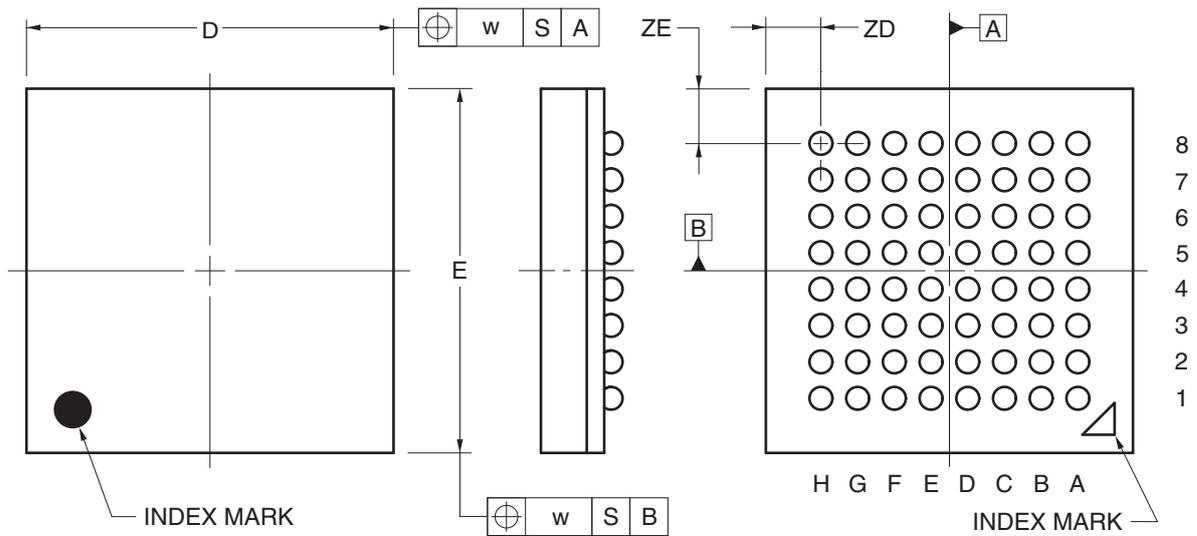
**NOTE**

1. Dimensions "※1" and "※2" do not include mold flash.
2. Dimension "※3" does not include trim offset.

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R5F100LCABG, R5F100LDABG, R5F100LEABG, R5F100LFABG, R5F100LGABG, R5F100LHABG,  
 R5F100LJABG  
 R5F101LCABG, R5F101LDABG, R5F101LEABG, R5F101LFABG, R5F101LGABG, R5F101LHABG,  
 R5F101LJABG  
 R5F100LCGBG, R5F100LDGBG, R5F100LEGBG, R5F100LFGBG, R5F100LGGBG, R5F100LHGBG,  
 R5F100LJGBG

JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-VFBGA64-4x4-0.40	PVBG0064LA-A	P64F1-40-AA2-2	0.03

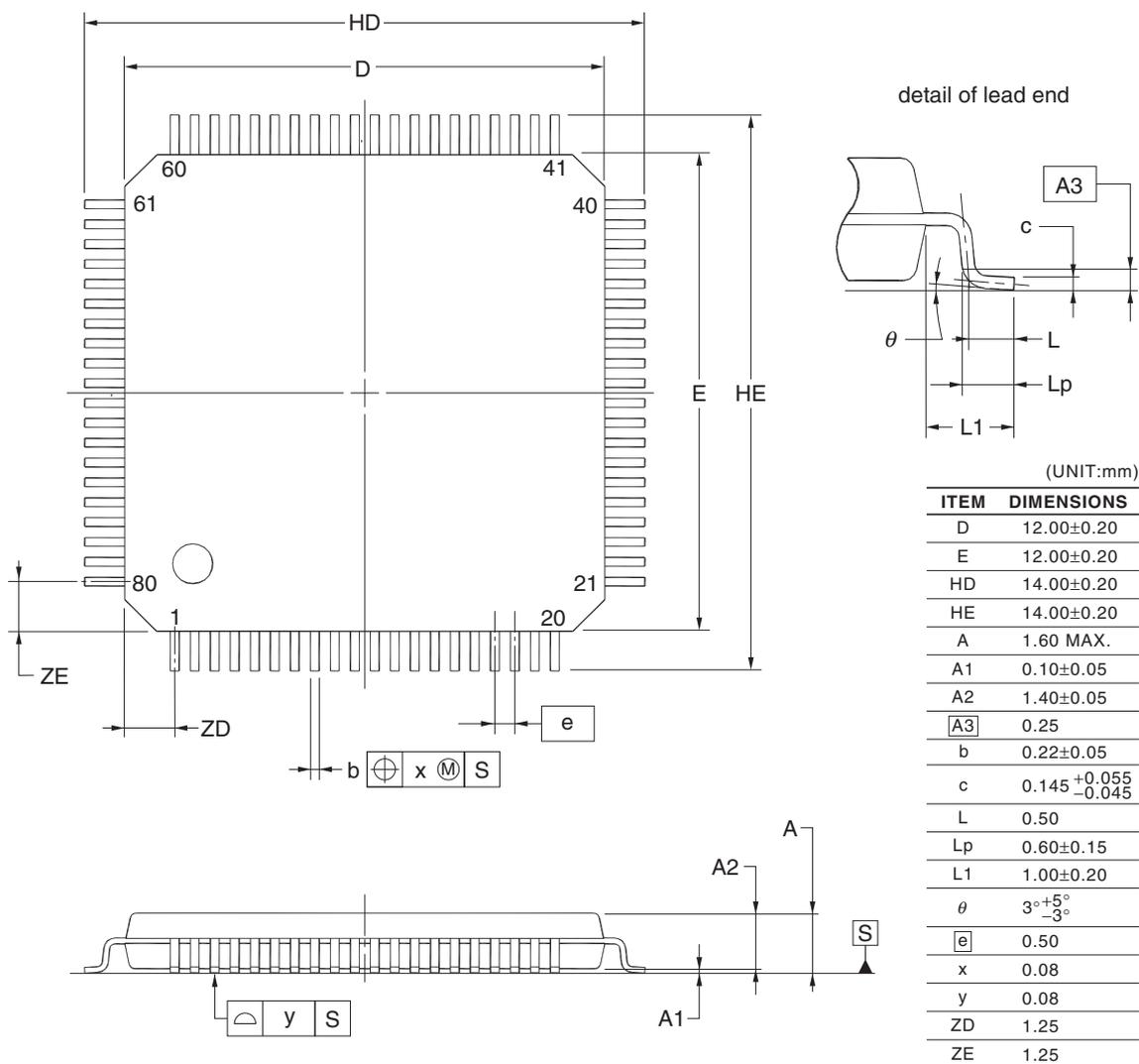


(UNIT:mm)

ITEM	DIMENSIONS
D	4.00±0.10
E	4.00±0.10
w	0.15
A	0.89±0.10
A1	0.20±0.05
A2	0.69
e	0.40
b	0.25±0.05
x	0.05
y	0.08
y1	0.20
ZD	0.60
ZE	0.60

R5F100MFAFB, R5F100MGAFB, R5F100MHAFB, R5F100MJAFB, R5F100MKAFB, R5F100MLAFB  
 R5F101MFAFB, R5F101MGAFB, R5F101MHAFB, R5F101MJAFB, R5F101MKAFB, R5F101MLAFB  
 R5F100MFDFB, R5F100MGDFB, R5F100MHDFB, R5F100MJDFB, R5F100MKDFB, R5F100MLDFB  
 R5F101MFDFB, R5F101MGDFB, R5F101MHDFB, R5F101MJDFB, R5F101MKDFB, R5F101MLDFB  
 R5F100MFGFB, R5F100MGGFB, R5F100MHGFB, R5F100MJGFB

JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-LFQFP80-12x12-0.50	PLQP0080KE-A	P80GK-50-8EU-2	0.53



**NOTE**  
 Each lead centerline is located within 0.08 mm of its true position at maximum material condition.

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Rev.	Date	Description	
		Page	Summary
3.00	Aug 02, 2013	81	Modification of figure of AC Timing Test Points
		81	Modification of description and note 3 in (1) During communication at same potential (UART mode)
		83	Modification of description in (2) During communication at same potential (CSI mode)
		84	Modification of description in (3) During communication at same potential (CSI mode)
		85	Modification of description in (4) During communication at same potential (CSI mode) (1/2)
		86	Modification of description in (4) During communication at same potential (CSI mode) (2/2)
		88	Modification of table in (5) During communication at same potential (simplified I <sup>2</sup> C mode) (1/2)
		89	Modification of table and caution in (5) During communication at same potential (simplified I <sup>2</sup> C mode) (2/2)
		91	Modification of table and notes 1 and 4 in (6) Communication at different potential (1.8 V, 2.5 V, 3 V) (UART mode) (1/2)
		92, 93	Modification of table and notes 2 to 7 in (6) Communication at different potential (1.8 V, 2.5 V, 3 V) (UART mode) (2/2)
		94	Modification of remarks 1 to 4 in (6) Communication at different potential (1.8 V, 2.5 V, 3 V) (UART mode) (2/2)
		95	Modification of table in (7) Communication at different potential (2.5 V, 3 V) (CSI mode) (1/2)
		96	Modification of table and caution in (7) Communication at different potential (2.5 V, 3 V) (CSI mode) (2/2)
		97	Modification of table in (8) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (1/3)
		98	Modification of table, note 1, and caution in (8) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (2/3)
		99	Modification of table, note 1, and caution in (8) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (3/3)
		100	Modification of remarks 3 and 4 in (8) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (3/3)
		102	Modification of table in (9) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (1/2)
		103	Modification of table and caution in (9) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (2/2)
		106	Modification of table in (10) Communication at different potential (1.8 V, 2.5 V, 3 V) (simplified I <sup>2</sup> C mode) (1/2)
		107	Modification of table, note 1, and caution in (10) Communication at different potential (1.8 V, 2.5 V, 3 V) (simplified I <sup>2</sup> C mode) (2/2)
		109	Addition of (1) I <sup>2</sup> C standard mode
		111	Addition of (2) I <sup>2</sup> C fast mode
		112	Addition of (3) I <sup>2</sup> C fast mode plus
		112	Modification of IICA serial transfer timing
		113	Addition of table in 2.6.1 A/D converter characteristics
113	Modification of description in 2.6.1 (1)		
114	Modification of notes 3 to 5 in 2.6.1 (1)		
115	Modification of description and notes 2, 4, and 5 in 2.6.1 (2)		
116	Modification of description and notes 3 and 4 in 2.6.1 (3)		
117	Modification of description and notes 3 and 4 in 2.6.1 (4)		